NSN 5962-01-100-5610



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-100-5610 **Body Length:** 1.285 inches **Body Width:** 0.600 inches **Body Height:** 0.175 inches **Maximum Power Dissipation Rating:** 1.8 watts **Operating Tempurature Range:** -55.0/+100.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and ultraviolet erasable and w/enable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 11 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 20.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Eprom Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

NSN 5962-01-100-5610

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0